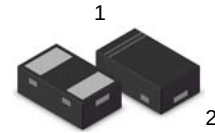


Applications

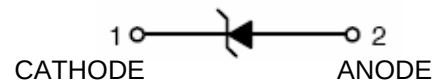
- | Cellular phones audio
- | MP3 players
- | Digital cameras
- | Portable applications
- | mobile telephone

Features

- | Small Body Outline Dimensions:
0.039" x 0.024" (1.0 mm x 0.60 mm)
- | Low Body Height: 0.020" (0.50 mm)
- | Stand-off Voltage: 5 V
- | Low Leakage
- | Response Time is Typically < 1 ns
- | ESD Rating of Class 3 (> 16 kV) per Human Body Model
- | IEC61000-4-2 Level 4 ESD Protection
- | These are Pb-Free Devices
- | We declare that the material of product compliance with RoHS requirements.
- | S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



SOD882



Ordering information

Device	Package	Reel Size	Qty / Reel
TPD6V8LP	SOD882	7 inch	10000

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air discharge		±15	kV
Contact discharge		±8	kV
ESD Voltage Per Human Body Model		16	kV
Total Power Dissipation on FR-5 Board (Note 1) @ T _A =25°C	PD	150	mW
Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C

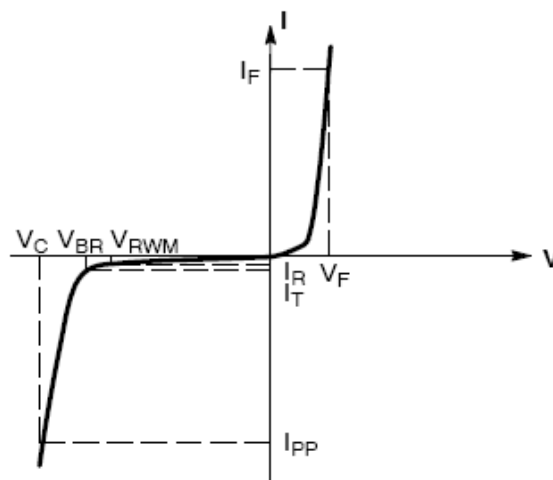
Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR 5= 1.0 x 0.75 x 0.62 in.

ELECTRICAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F
P_{pk}	Peak Power Dissipation
C	Max. Capacitance @ $V_R = 0$ and $f = 1\text{ MHz}$



Uni-Directional TVS

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted, $V_F=0.9\text{V}$ Max. @ $I_F=10\text{mA}$ for all types)

Device	V_{RWM} (V)	I_R (μA) @ V_{RWM}	V_{BR} (V) @ I_T (Note 2)	I_T (mA)	I_{PP} (A) (Note 3)	V_C (V) @ Max I_{PP} (Note 3)	P_{PK} (W) (8*20 μs)	C (pF)
	Max	Max	Min		Max	Max	Typ	Typ
TPD6V8LP	5.0	1.0	6.2	1.0	8.7	12.3	107	65

- V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C
- Surge current waveform per Figure 3.

TYPICAL CHARACTERISTICS

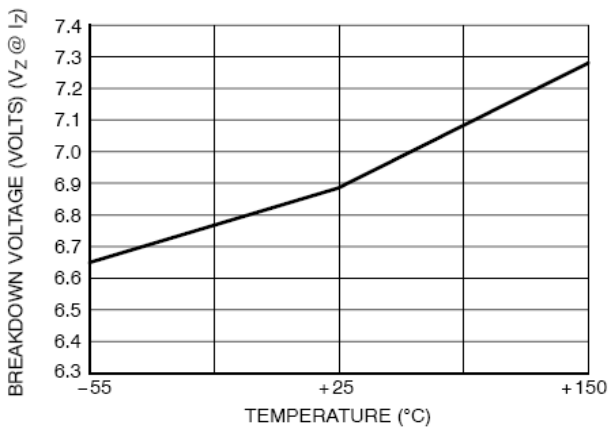


Figure 1. Typical Breakdown Voltage versus Temperature

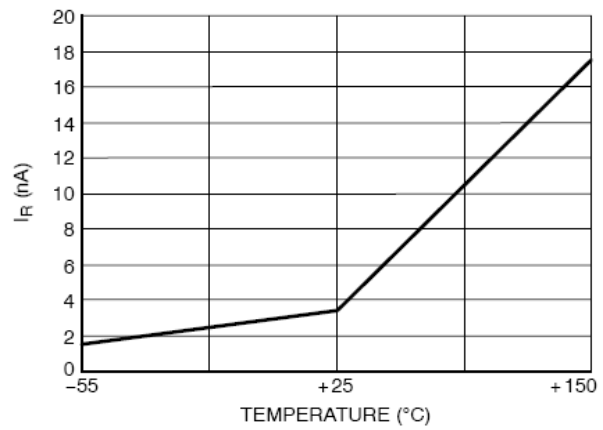


Fig 2. Typical Leakage Current versus Temperature

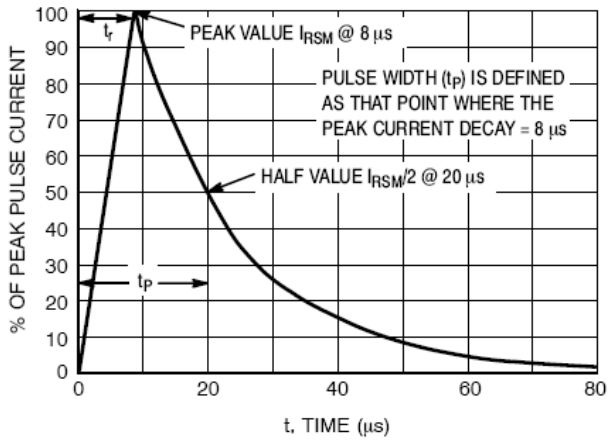


Figure 3. 8*20 μ s Pulse Waveform

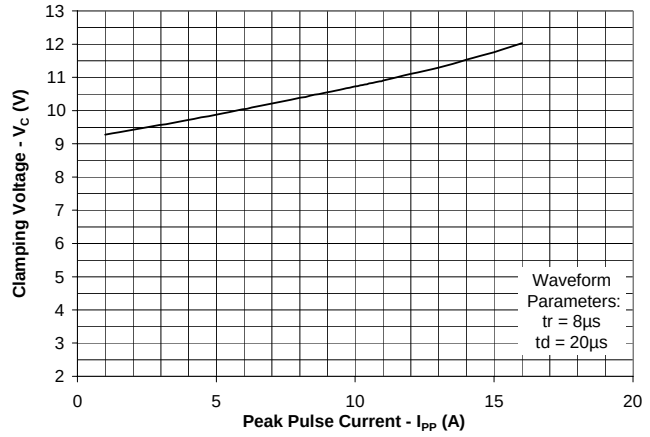


Fig 4. Normalized Junction Capacitance Voltage vs. Reverse Voltage

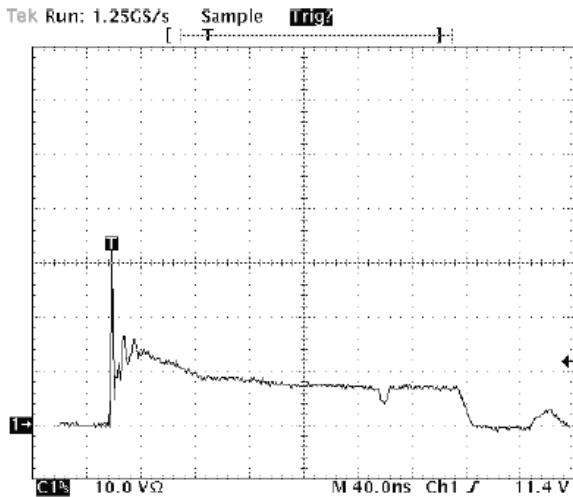


Figure 5. Positive 8kV contact per IEC 61000-4-2

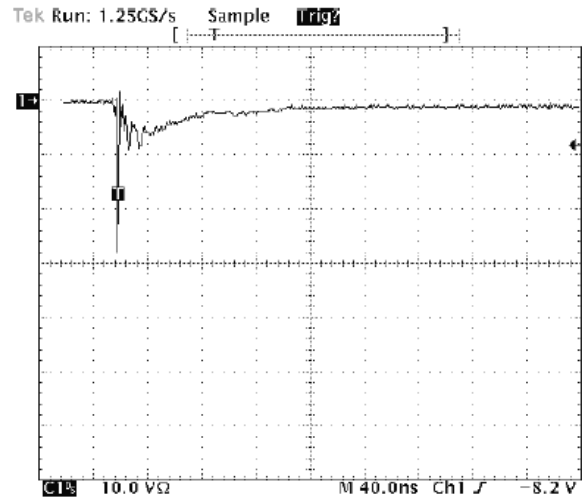
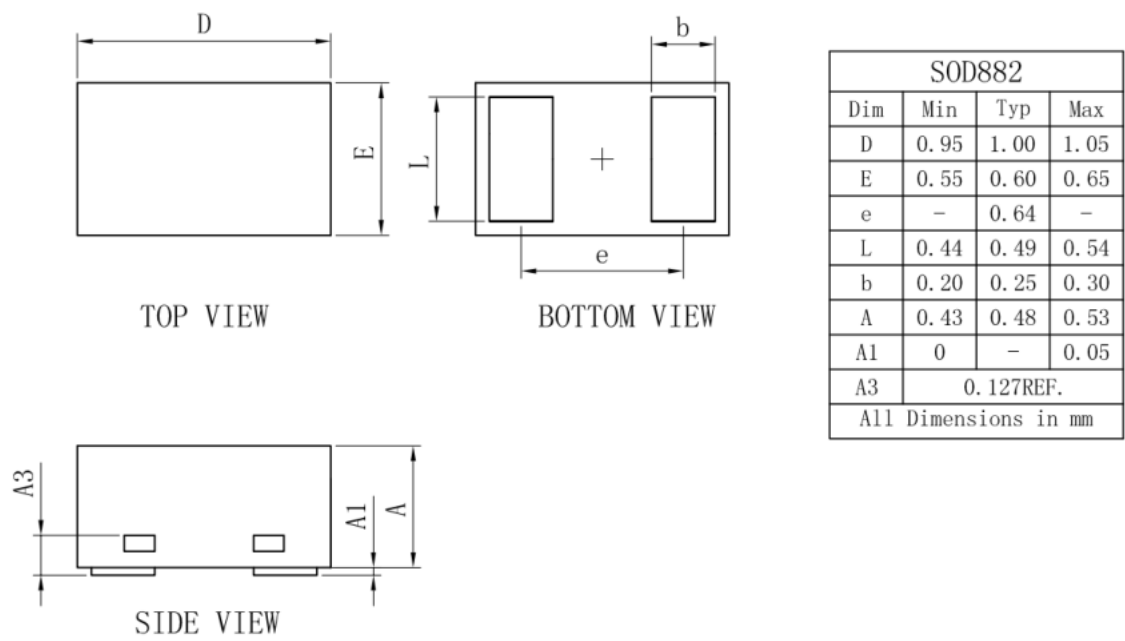


Fig 6. Negative 8kV contact per IEC 61000-4-2

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SOLDERING FOOTPRINT

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